

Multiple Bipolar Transistors—Quad

Device	Type	V _{CE} (V) Min	I _C (A) Max	f _{CE} @ I _C		f _T (MHz) Min	C _{OB} (pF) Max	V _{CE(SAT)} Volts @ I _C /I _B & I _C			Config-uration	Package
				Min	mA			Max		mA		
MMPO6602	BOTH	30	0.5	100	150	200	8	0.4	10	150	CD7	SOIC-16
MPO6602	BOTH	30	0.5	100	150	200	8	0.4	10	150	CD3	TO-116
MMPO6700	BOTH	40	0.2	70	10	200	4.5	0.25	10	1	CD7	SOIC-16
MPO6700	BOTH	40	0.2	70	10	200	4.5	0.25	10	1	CD3	TO-116
MMPO2369	NPN	15	0.5	40	10	450	4	0.25	10	10	CD5	SOIC-16
MPO2369	NPN	15	0.5	40	10	450	4	0.25	10	10	CD1	TO-116
MMPO2222	NPN	30	0.5	100	150	200	8	0.4	10	150	CD5	SOIC-16
MPO2222	NPN	30	0.5	100	150	200	8	0.4	10	150	CD1	TO-116
MMPO3724	NPN	36	1	35	500	300	12	0.32	10	300	CD5	SOIC-16
MPO3724	NPN	36	1	35	500	300	12	0.32	10	300	CD1	TO-116
MMPO3725	NPN	40	1	25	500	250	10	0.45	10	500	CD5	SOIC-16
MPO3725	NPN	40	1	25	500	250	10	0.45	10	500	CD1	TO-116
MMPO3904	NPN	40	0.2	75	10	250	4	0.2	10	10	CD5	SOIC-16
MPO3904	NPN	40	0.2	75	10	250	4	0.2	10	10	CD1	TO-116
MMPO2222A	NPN	40	0.5	100	150	200	8	0.3	10	150	CD5	SOIC-16
MMPO2907	PNP	40	0.6	100	150	200	8	0.4	10	150	CD6	SOIC-16
MPO2907	PNP	40	0.6	100	150	200	8	0.4	10	150	CD2	TO-116
MMPO3467	PNP	40	1	40	500	175	25	0.5	10	500	CD6	SOIC-16
MPO3467	PNP	40	1	40	500	175	25	0.5	10	500	CD2	TO-116
MMPO3906	PNP	40	0.2	75	10	200	4.5	0.25	10	10	CD6	SOIC-16
MPO3906	PNP	40	0.2	75	10	200	4.5	0.25	10	10	CD2	TO-116
MMPO2907A	PNP	60	0.6	100	150	200	8	0.4	10	150	CD6	SOIC-16

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